







TPS62A01, TPS62A01A, TPS62A02, TPS62A02A, TPS62A02N, TPS62A02NA

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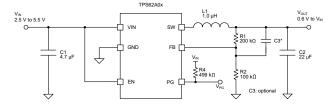
TPS62A0x, TPS62A0xA, and TPS62A02Nx 1A, 2A, High-Efficiency, Synchronous Buck Converters in a SOT-563 and a SOT-23 Package

1 Features

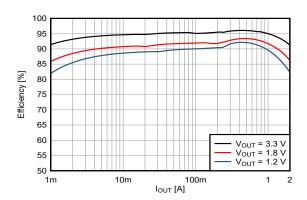
- 2.5V to 5.5V input voltage range
- 0.6V to V_{IN} adjustable output voltage range
- 180m $\Omega/120$ m Ω low R_{DSON} switches (1A DRL)
- 100m Ω /67m Ω low R_{DSON} switches (1A DDC, 2A)
- < 23µA quiescent current
- 1% feedback accuracy (0°C to 125°C)
- 100% mode operation
- 2.4MHz switching frequency
- Power save mode or PWM option available
- Power-good output pin (optional)
- Short-circuit protection (HICCUP)
- Internal soft start-up
- Active output discharge
- Thermal shutdown protection
- Pin-to-pin compatible with the TLV62585 (DRL)
- Pin-to-pin compatible with the TLV62569 (DDC)

2 Applications

- Set top box, TV applications
- IP network camera, Multi-function printer
- Wireless router, solid state drive
- Battery-powered applications
- General purpose point-of-load supply



Typical Application



Efficiency vs Output Current at 5V_{IN} (TPS62A02x)

3 Description

The TPS62A0x family of devices are synchronous step-down buck DC/DC converters optimized for high efficiency and compact design size. The devices integrate switches capable of delivering an output current up to 2A. At medium to heavy loads, the devices operate in pulse width modulation (PWM) mode with 2.4MHz switching frequency. At light load, the devices automatically enter power save mode (PSM) to maintain high efficiency over the entire load current range. In shutdown, the current consumption is minimal as well. The TPS62A0xA variants of this device family operate in forced PWM across the whole load current range.

The TPS62A0x devices provide an adjustable output voltage through an external resistor divider. An internal soft-start circuit limits the inrush current during start-up. Other features like overcurrent protection, thermal shutdown protection, and power good (optional) are built-in. The devices are available in a SOT563 and SOT23-6 package.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾				
TPS62A01x	DRL (SOT-563, 6)	1.60mm × 1.60mm				
	DDC (SOT-23, 6)	2.90mm × 2.80mm				
TDS62A02v	DRL (SOT-563, 6)	1.60mm × 1.60mm				
TPS02AU2X	DDC (SOT-23, 6)	2.90mm × 2.80mm				
TPS62A02Nx	DRL (SOT-563, 6)	1.60mm × 1.60mm				
TPS62A02x	DDC (SOT-23, 6) DRL (SOT-563, 6) DDC (SOT-23, 6)	2.90mm × 2.80mm 1.60mm × 1.60mm 2.90mm × 2.80mm				

- (1)For more information, see Section 11.
- The package size (length × width) is a nominal value and includes pins, where applicable.

Device Information

PART NUMBER ⁽¹⁾ OPERATION MODE		OUTPUT CURRENT	PIN 6		
TPS62A01	PSM, PWM	1A			
TPS62A01A	FPWM	IA IA			
TPS62A02	PSM, PWM		PG		
TPS62A02A	FPWM	2A			
TPS62A02N	PSM, PWM		OUT		
TPS62A02NA	FPWM		001		

See the Device Comparison Table.



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4 Device Comparison Table

Device Number	Output Current	Package	Operation Mode	Pin 6
TPS62A01DRLR	1A		PSM, PWM	
TPS62A01ADRLR	IA		FPWM	PG
TPS62A02DRLR		SOT-563, 6	PSM, PWM	PG
TPS62A02ADRLR	2A	301-303, 0	FPWM	
TPS62A02NDRLR			PSM, PWM	OUT
TPS62A02NADRLR			FPWM	001
TPS62A01PDDCR	1A		PSM, PWM	
TPS62A01APDDCR	IA	SOT-23, 6	FPWM	PG
TPS62A02PDDCR	2A	301-23, 0	PSM, PWM	, FG
TPS62A02APDDCR	ZA	-	FPWM	

5 Pin Configuration and Functions

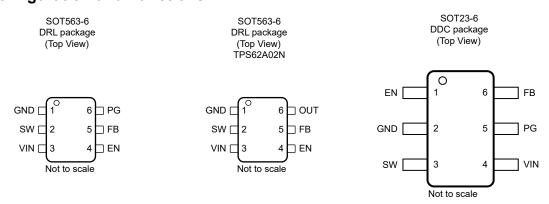


Figure 5-1. 6-Pin DRL SOT-563 Package (Top View), 6-Pin DDC SOT-23 Package (Top View)

Table 5-1. Pin Functions

	Pin Number	•	Type ⁽¹⁾	Description
Name	SOT563-6	SOT23-6	туресч	Description
EN	4	1	I	Device enable logic input. Logic high enables the device. Logic low disables the device and turns the device into shutdown. Do not leave the pin floating.
FB 5 6		6	I	Feedback pin for the internal control loop. Connect this pin to an external feedback divider.
GND	1	2	G	Ground pin.
PG	PG 6 5		0	Power-good open-drain output pin. The pullup resistor cannot be connected to any voltage higher than 5.5V. If unused, leave the pin open or connect to GND.
OUT ⁽²⁾		1	I	Output voltage sense pin.
SW 2 3		0	Switch pin connected to the internal FET switches and inductor terminal. Connect the inductor of the output filter to this pin.	
VIN	3	4	I	Input voltage pin. Connect the input capacitor as close as possible between V_{IN} and $\overline{\text{GND}}$.

- (1) I = Input, O = Output, G = Ground.
- (2) Only for TPS62A0xN versions.

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Pin voltage ⁽²⁾	VIN, EN, PG	-0.3	6.5	V
	SW, DC	-0.3	V _{IN} + 0.3	V
	SW, transient < 10 ns	-3.0	10	V
	FB	-0.3	3	V
T _J	Operating junction temperature	-40	150	°C
T _{stg}	Storage temperature	-55	150	°C

⁽¹⁾ Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

			VALUE	UNIT
V	V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
(ESD)		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 (2)	±500	v

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating junction temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V _{IN}	Input supply voltage range		2.5		5.5	V
V _{OUT}	Output voltage range	Output voltage range			V _{IN}	V
I _{OUT}	Output current range	TPS62A01	0		1	Α
I _{OUT}	Output current range (1)	TPS62A02	0		2	Α
L	Effective inductance			1.0		μH
C _{OUT}	Output capacitance	V _{OUT} < 1.2 V		44		μF
C _{OUT}	Output capacitance	1.2 V ≤ V _{OUT} < 1.8 V		22		μF
C _{OUT}	Output capacitance	V _{OUT} ≥ 1.8 V		10		μF
I _{PG}	Power Good input current capability		0		1	mA
TJ	Operating junction temperature	·	-40		125	°C

⁽¹⁾ Operating continuously at 2-A with input voltages < 3.3V or at ambient temperatures > 85 °C might result in thermal shutdown, per EVM measurements.

6.4 Thermal Information

		TPS62A0x	TPS62A0x	
THERMAL METRIC ⁽¹⁾		DRL	DDC	UNIT
		6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	157.3	132.1	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	92.2	74.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	45.6	45.5	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	4.0	25.5	°C/W

⁽²⁾ All voltage values are with respect to the network ground terminal.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information (continued)

		TPS62A0x	TPS62A0x	
THERMAL METRIC ⁽¹⁾		DRL	DDC	UNIT
		6 PINS	6 PINS	
ψ _{JB} Junction-to-board characterization parameter		45.0	45.1	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics report.

6.5 Electrical Characteristics

 $T_J = -40$ °C to +125°C, $V_{IN} = 2.5$ V to 5.5 V. Typical values are at $T_J = 25$ °C and $V_{IN} = 5$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
I _{Q(VIN)}	VIN quiescent current	Non-switching; V _{EN} = High; V _{FB} = 610 mV; TPS62A01xDRL		20		μA
I _{Q(VIN)}	VIN quiescent current	Non-switching; V _{EN} = High; V _{FB} = 610 mV; TPS62A01xDDC; TPS62A02		23		μA
I _{SD(VIN)}	VIN shutdown supply current	V _{EN} = Low		0.01	2	μA
UVLO						
V _{UVLO(R)}	VIN UVLO rising threshold	V _{IN} rising	2.3	2.4	2.5	V
V _{UVLO(F)}	VIN UVLO falling threshold	V _{IN} falling	2.2	2.3	2.4	٧
ENABLE						
V _{EN(R)}	EN voltage rising threshold	EN rising; enable switching	1.2			V
V _{EN(F)}	EN voltage falling threshold	EN falling, disable switching			0.4	٧
V _{EN(LKG)}	EN Input leakage current	V _{EN} = 5 V			100	nA
REFERENCE VO	DLTAGE					
V _{FB}	FB voltage	T _J = 0°C to 125°C, PWM mode	594	600	606	mV
V _{FB}	FB voltage	PWM mode	591	600	609	mV
I _{FB(LKG)}	FB input leakage current	V _{FB} = 0.6 V			100	nA
SWITCHING FR	EQUENCY					
f _{SW(FCCM)}	Switching frequency, FPWM operation	V _{IN} = 5 V; V _{OUT} = 1.8 V		2400		kHz
STARTUP	1					
	Internal fixed soft-start time	From EN = High to V _{FB} = 0.56 V			1	ms
POWER STAGE						
R _{DSON(HS)}	High-side MOSFET on-resistance	TPS62A01xDRL; V _{IN} = 5 V		180		mΩ
R _{DSON(LS)}	Low-side MOSFET on-resistance	TPS62A01xDRL; V _{IN} = 5 V		120		mΩ
R _{DSON(HS)}	High-side MOSFET on-resistance	V _{IN} = 5 V; TPS62A01xDDC; TPS62A02		100		mΩ
R _{DSON(LS)}	Low-side MOSFET on-resistance	V _{IN} = 5 V; TPS62A01xDDC; TPS62A02		67		mΩ
OVERCURRENT	F PROTECTION					
I _{HS(OC)}	High-side peak current limit	TPS62A01	1.3	1.8		Α
I _{LS(OC)}	Low-side valley current limit	TPS62A01		1.8		Α
I _{HS(OC)}	High-side peak current limit	TPS62A02	2.7	3.4		Α
I _{LS(OC)}	Low-side valley current limit	TPS62A02xDRL		4.2		Α
I _{LS(OC)}	Low-side valley current limit	TPS62A02xDDC		3.15		Α
POWER GOOD						
V _{PGTH}	Power Good threshold	PG low, FB falling		93.5		%
V _{PGTH}	Power Good threshold	PG high, FB rising		96		%
	PG delay falling			35		μs
	PG delay rising			10		μs
I _{PG(LKG)}	PG pin Leakage current when open drain output is high	V _{PG} = 5 V			100	nA
	The state of the s					



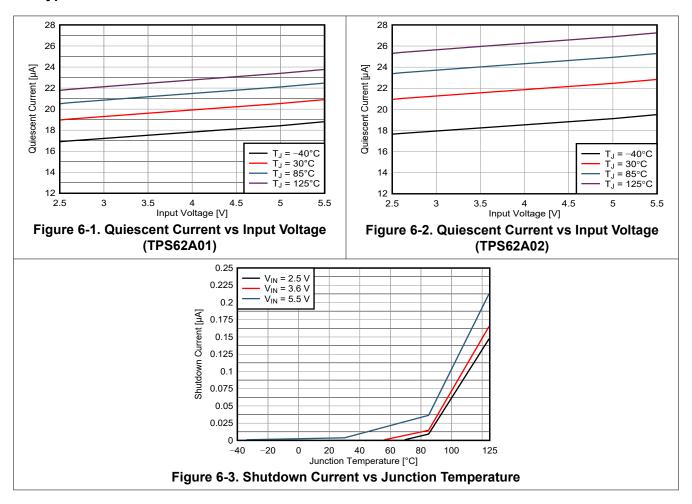
6.5 Electrical Characteristics (continued)

 $T_J = -40$ °C to +125°C, $V_{IN} = 2.5$ V to 5.5 V. Typical values are at $T_J = 25$ °C and $V_{IN} = 5$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Output discharge current on SW pin	V _{IN} = 3 V, V _{OUT} = 2.0 V; TPS62A01xDRL		60		mA
	Output discharge current on SW pin	V _{IN} = 3 V, V _{OUT} = 2.0 V; TPS62A01xDDC; TPS62A02		76		mA
THERMAL SHUTDO	OWN					
T _{J(SD)}	Thermal shutdown threshold	Temperature rising		170		°C
T _{J(HYS)}	Thermal shutdown hysteresis			20		°C



6.6 Typical Characteristics

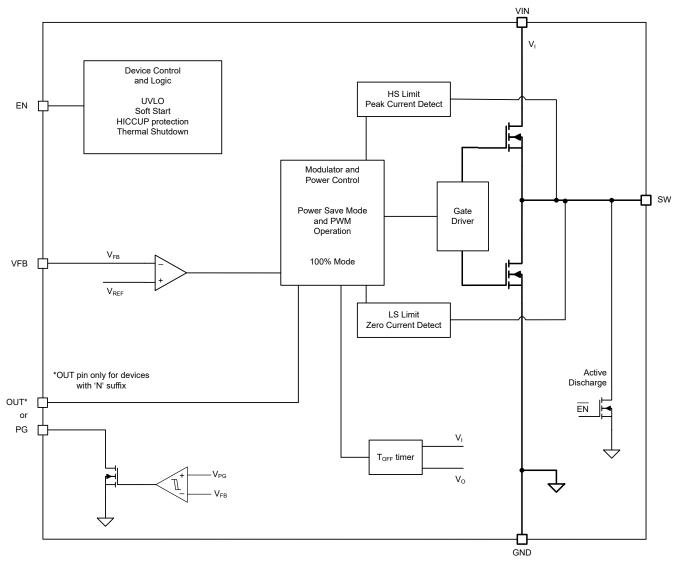


7 Detailed Description

7.1 Overview

The TPS62A0x is a high-efficiency synchronous step-down converter. The device operates with an adaptive off time with a peak current control scheme. The device operates typically at 2.4MHz frequency pulse width modulation (PWM) at moderate to heavy load currents. Based on the V_{IN}/V_{OUT} ratio, a simple circuit sets the required off time for the low-side MOSFET, making the switching frequency relatively constant regardless of the variation of the input voltage, output voltage, and load current.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Power Save Mode

The device automatically enters power save mode to improve efficiency at light load when the inductor current becomes discontinuous. In power save mode, the converter reduces the switching frequency and minimizes current consumption. In power save mode, the output voltage rises slightly above the nominal output voltage. This effect is minimized by increasing the output capacitor or adding a feedforward capacitor.



7.3.2 100% Duty Cycle Low Dropout Operation

The device offers low input-to-output voltage difference by entering 100% duty cycle mode. In this mode, the high-side MOSFET switch is constantly turned on and the low-side MOSFET is switched off. The minimum input voltage to maintain output regulation, depending on the load current and output voltage, is calculated as:

$$V_{IN(MIN)} = V_{OUT} + I_{OUT} \times (R_{DS(ON)} + R_L)$$
(1)

where

- R_{DS(ON)} = High-side FET on-resistance
- R_L = Inductor ohmic resistance (DCR)

7.3.3 Soft Start

After enabling the device, internal soft-start circuitry ramps up the output voltage, which reaches the nominal output voltage during start-up time, avoiding excessive inrush current and creating a smooth voltage rise slope. Internal soft-start circuitry also prevents excessive voltage drops of primary cells and rechargeable batteries with high internal impedance.

The TPS62A0x is able to start into a prebiased output capacitor. The converter starts with the applied bias voltage and ramps the output voltage to the nominal value.

7.3.4 Switch Current Limit and Short-Circuit Protection (HICCUP)

The switch current limit prevents the device from high inductor current and drawing excessive current from the battery or input rail. Due to internal propagation delay, the AC peak current can exceed the static current limit during that time. Excessive current can occur with a shorted or saturated inductor, an overload or shorted output circuit condition. If the inductor current reaches the threshold I_{LIM}, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current with an adaptive off time.

When this switch current limit is triggered 32 times, the device stops switching to protect the output. The device then automatically starts a new start-up after a typical delay time of 100µs has passed. This is named HICCUP short-circuit protection. The device repeats this mode until the high load condition disappears. HICCUP protection is also enabled during the start-up.

7.3.5 Undervoltage Lockout

To avoid misoperation of the device at low input voltages, an undervoltage lockout (UVLO) is implemented, which shuts down the device at voltages lower than V_{UVLO} .

7.3.6 Thermal Shutdown

The device goes into thermal shutdown and stops switching when the junction temperature exceeds T_{JSD} . When the device temperature falls below the threshold by 20°C, the device returns to normal operation automatically.

7.4 Device Functional Modes

7.4.1 Enable and Disable

The device is enabled by setting the EN input to a logic High. Accordingly, a logic Low disables the device. If the device is enabled, the internal power stage starts switching and regulates the output voltage to the set point voltage. The EN input must be terminated and not be left floating.

7.4.2 Power Good

The TPS62A0x (except devices with 'N' suffix) has a built-in power-good (PG) feature to indicate whether the output voltage has reached the target and the device is ready. The PG signal can be used for start-up sequencing of multiple rails. The PG pin is an open-drain output that requires a pullup resistor to any voltage up to the recommended input voltage level. PG is low when the device is turned off due to EN, UVLO (undervoltage lockout), or thermal shutdown. VIN must remain present for the PG pin to stay low. If not used, the power-good



can be tie to GND or left open. The PG indicator has a de-glitch to avoid the signal indicating glitches or transient responses from the loop.

Table 7-1. Power-Good indicator Functional Table

	Logic Signals								
V _I	EN Pin	Thermal Shutdown	v _o	PG Status					
		V _O on target		High Impedance					
V _I > UVLO	HIGH	NO	V _O < target	LOW					
			YES	LOW					
		YES	х	LOW					
	LOW	х	х	LOW					
V _I < 1.8V	Х	X	Х	Undefined					



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

8.2 Typical Application

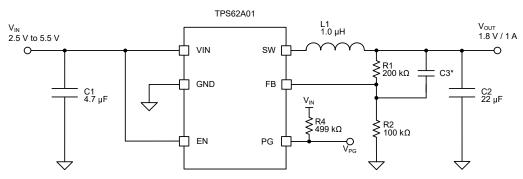


Figure 8-1. TPS62A01 Typical Application Circuit

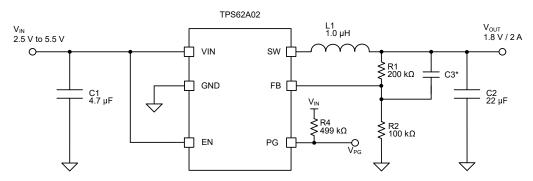


Figure 8-2. TPS62A02 Typical Application Circuit

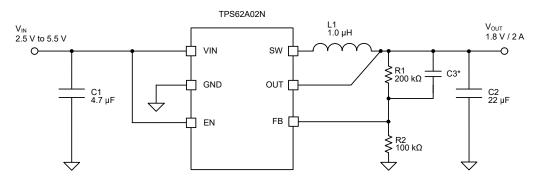


Figure 8-3. TPS62A02N Typical Application Circuit

*C3 is optional

8.2.1 Design Requirements

For this design example, use the parameters listed in Table 8-1 as the input parameters

Table 8-1. Design Parameters

Design Parameter	Example Value
Input voltage	2.5V to 5.5V
Output voltage	1.8V
Maximum output current	1.0A, 2.0A

Table 8-2 lists the components used for the example.

Table 8-2. List of Components

Reference	Description	Manufacturer ⁽¹⁾
C1	4.7μF, Ceramic Capacitor, 10V, X7R, size 0805, GRM21BR71A475KA73L	Murata
C2	22μF, Ceramic Capacitor, 10V, X7R, size 0805, GRM21BZ71A226KE15L	Murata
L1	1μH, Power Inductor, DFE252012F-1R0M (1A) / XGL3520-102MEC (2A)	Murata / Coilcraft
R1, R2	Chip resistor, 1%, size 0603	Std.
C3	Optional, 120pF if needed	Std.

⁽¹⁾ See the Third-Party Products Disclaimer.

8.2.2 Detailed Design Procedure

8.2.2.1 Setting the Output Voltage

The output voltage is set by an external resistor divider according to Equation 2.

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1\right) = R2 \times \left(\frac{V_{OUT}}{0.6 V} - 1\right)$$
(2)

R2 must not be higher than $100k\Omega$ to provide acceptable noise sensitivity.

8.2.2.2 Output Filter Design

The inductor and output capacitor together provide a low-pass filter. To simplify this process, Table 8-3 outlines possible inductor and capacitor value combinations. Checked cells represent combinations that are proven for stability by simulation and lab test. Check further combinations for each individual application.

Table 8-3. Matrix of Output Capacitor and Inductor Combinations for TPS62A01 and TPS62A02

V _{OUT} [V]	L [μH] ⁽¹⁾	C _{OUT} [µF] ⁽²⁾						
4001 [4]	_ [μιι]` ΄	10	22	2 × 22				
0.6 ≤ V _{OUT} < 1.2			+	++(3)				
1.2 ≤ V _{OUT} < 1.8	1		++(3)	+				
1.8 ≤ V _{OUT}		+(4)	++(3)	+				

- (1) Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by +20% and -30%.
- (2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by +20% and -50%.
- (3) This LC combination is the standard value and recommended for most applications.
- (4) The minimum C_{OUT} of $10\mu F$ does not support an additional feedforward capacitor.

A 0.47uH inductor can also be used with the same recommended output capacitors for the TPS62A02x. In case a lower output ripple is desired, higher output capacitance can help reduce the ripple.

8.2.2.3 Input and Output Capacitor Selection

The architecture of the TPS62A0x allows use of tiny ceramic-type output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are thus recommended. To keep



resistance up to high frequencies and to achieve narrow capacitance variation with temperature, TI recommends to use X7R or X5R dielectric.

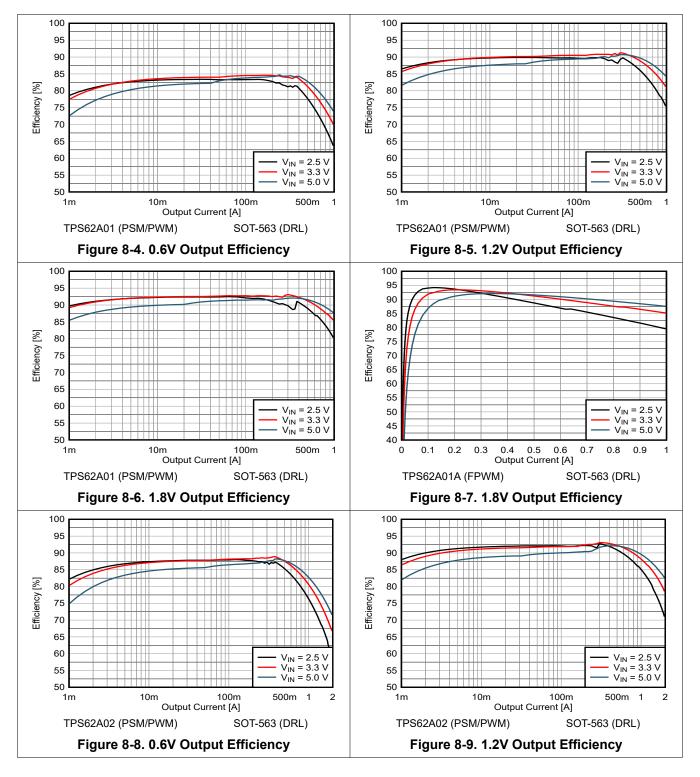
The input capacitor is the low impedance energy source for the converter that helps provide stable operation. TI recommends a low-ESR multilayer ceramic capacitor for best filtering. For most applications, a 4.7µF input capacitor is sufficient; a larger value reduces input voltage ripple.

The TPS62A0x is designed to operate with an output capacitor of $10\mu\text{F}$ to $47\mu\text{F}$, depending on the selected output voltage, as outlined in Table 8-3.

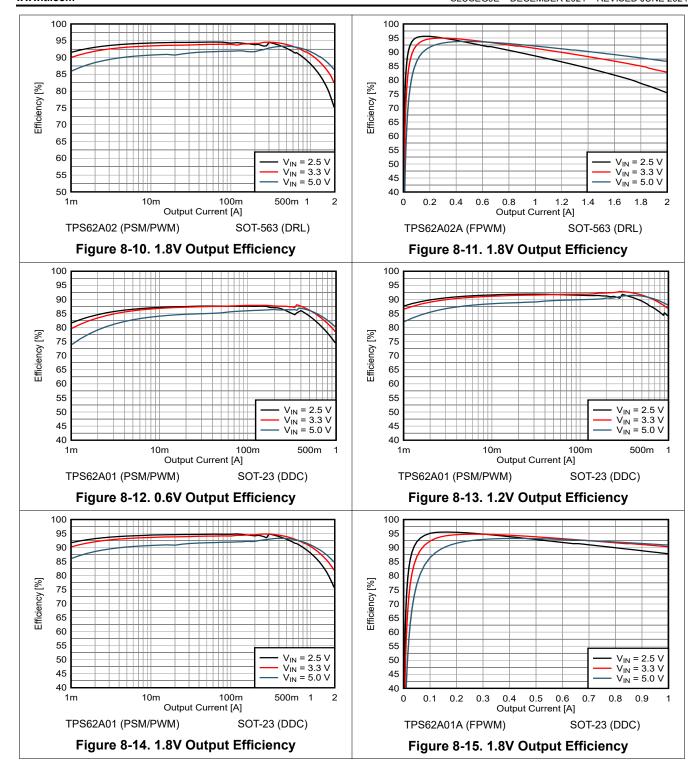
A feedforward capacitor reduces the output ripple in PSM and improves the load transient response. A 120pF capacitor is good for the 1.8V output typical application.



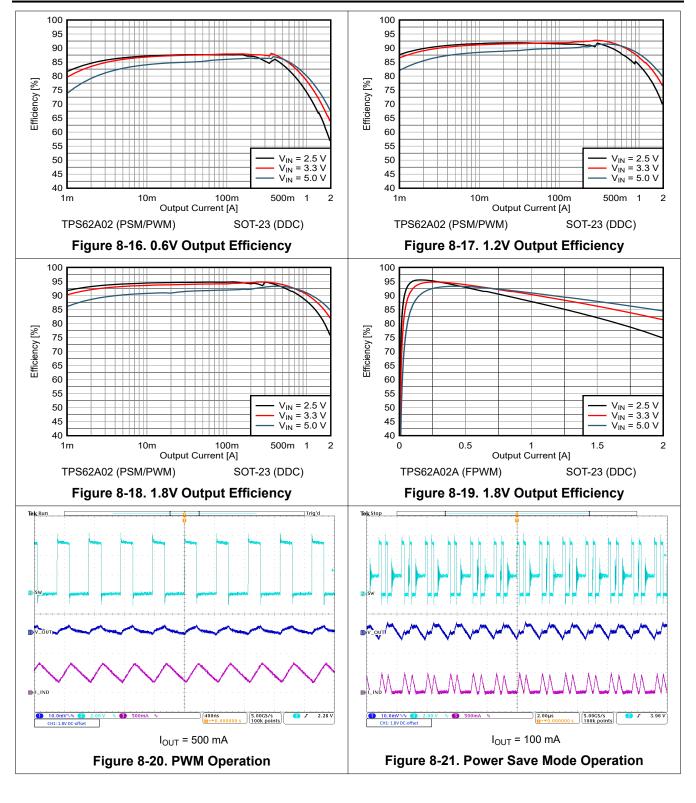
8.2.3 Application Curves

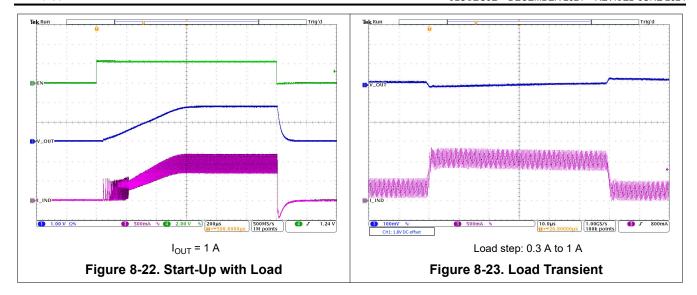












8.3 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 2.5V to 5.5V. Make sure that the input power supply has a sufficient current rating for the application.

8.4 Layout

8.4.1 Layout Guidelines

The printed-circuit-board (PCB) layout is an important step to maintain the high performance of the TPS62A01x and TPS62A02x devices.

- Place the input and output capacitors and the inductor as close as possible to the IC. This action keeps
 the power traces short. Routing these power traces direct and wide results in low trace resistance and low
 parasitic inductance.
- Connect the low side of the input and output capacitors properly to the GND pin to avoid a ground potential shift.
- The sense traces connected to FB is a signal trace. Take special care to avoid noise being induced. Keep these traces away from SW nodes.
- Use a common ground. GND layers can be used for shielding.

See Figure 8-24 and Figure 8-25 for the recommended PCB layout.

8.4.2 Layout Example

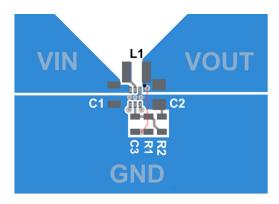


Figure 8-24. TPS62A0x (SOT563) PCB Layout Recommendation



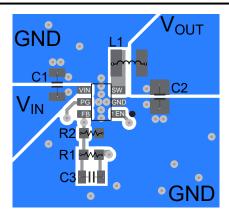


Figure 8-25. TPS62A0x (SOT23-6) PCB Layout Recommendation



9 Device and Documentation Support

9.1 Device Support

9.1.1 Third-Party Products Disclaimer

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9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.



10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (April 2024) to Revision E (June 2024)	Page
Changed device status of TPS62A02Nx versions and devices in DDC package from preview	to production
throughout the data sheet	3
Changes from Revision C (December 2023) to Revision D (April 2024)	Page
Added devices with 'N' suffix throughout the data sheet	1
Changed absolute maximum voltage of VIN, EN and PG from 6V to 6.5V	4
Updated block diagram to include devices with 'N' suffix (OUT instead of PG)	8
Changes from Revision B (July 2022) to Revision C (December 2023)	Page
Added DDC package option throughout the data sheet	3
Changed ESD Ratings CDM row from showing testing was per JESD22-C101 to show that to JS-002	•
- Changed block diagram PG circuit by swapping V_{PG} and V_{FB}	

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS62A01ADRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	1J8
TPS62A01ADRLR.A	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1J8
TPS62A01APDDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	A01AP
TPS62A01APDDCR.A	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A01AP
TPS62A01DRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	1J7
TPS62A01DRLR.A	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1J7
TPS62A01PDDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	A01P
TPS62A01PDDCR.A	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A01P
TPS62A02ADRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	1JM
TPS62A02ADRLR.A	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1JM
TPS62A02APDDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	A02AP
TPS62A02APDDCR.A	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A02AP
TPS62A02DRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	1JL
TPS62A02DRLR.A	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1JL
TPS62A02NADRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	1SC
TPS62A02NADRLR.A	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1SC
TPS62A02NDRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1SB
TPS62A02NDRLR.A	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1SB
TPS62A02PDDCR	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	A02P
TPS62A02PDDCR.A	Active	Production	SOT-23- THIN (DDC) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A02P

⁽¹⁾ Status: For more details on status, see our product life cycle.

PACKAGE OPTION ADDENDUM

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- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TPS62A01, TPS62A01A, TPS62A02, TPS62A02A:

Automotive: TPS62A01-Q1, TPS62A01A-Q1, TPS62A02-Q1, TPS62A02A-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62A01ADRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A01APDDCR	SOT-23- THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS62A01DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A01PDDCR	SOT-23- THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS62A02ADRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A02APDDCR	SOT-23- THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS62A02DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.8	1.8	0.75	4.0	8.0	Q3
TPS62A02DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.8	1.8	0.75	4.0	8.0	Q3
TPS62A02DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A02NADRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A02NDRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A02PDDCR	SOT-23- THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62A01ADRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A01APDDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0
TPS62A01DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A01PDDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0
TPS62A02ADRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A02APDDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0
TPS62A02DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A02DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A02DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A02NADRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A02NDRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A02PDDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0



SMALL OUTLINE TRANSISTOR



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-193.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

 7. Board assembly site may have different recommendations for stencil design.





PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-293 Variation UAAD



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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